



# Effects of Concentration on the Sensing Properties of Rgo/ CuO Nanoparticles as Ammonia Gas Sensor

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This study proposed a low-cost and straightforward hydrothermal method to prepare reduced graphene oxide/copper oxide (rGO/CuO) nanocomposites at 100 °C for different amounts of rGO. In this method, the reduction of graphene oxide and the formation of copper oxide occur using NaOH as the reducing agent at low temperatures, and then the structural, morphological, and optical properties are evaluated. The results of XRD showed that the prominent peaks related to the formation of rGO/CuO were observed. The particle size of nanoparticles was calculated and found to increase after annealing to 400 °C. The morphological results revealed the formation of two structures, rod and spherical- shape, according to the difference in the GO ratios in the nanocomposites. The results of TGA illustrated the thermal stability of rGO/CuO compared to pure GO. They showed that the stability depends on the GO concentration in the nanocomposite, which decreased with increasing GO concentration. The fabricated sensors with pure CuO and rGO/CuO composites were tested for ammonia detection at different temperatures. The rGO/CuO nanocomposites sensor showed a three-fold improvement in sensor response compared to a bare CuO sensor at room temperature, in addition to rapid response and recovery time of about 21seconds and 15 seconds, respectively.

**Keywords:** N Reduced graphene oxide, copper oxide, gas sensor, and hydrothermal method, sensitivity.

## 1. Introduction

Nanoscience and nanotechnology refer to the production, characterization, and development of the applications of tiny particles ranging between 1 and 100 nm. 1,2,3. Among nanoparticles, metal oxide nanoparticles have become very popular in recent decades due to

their amazing properties. 4,5,6. Copper oxide (CuO) has good magnetic, electrical, physical, and optical properties. It has attracted considerable attention in a variety of applications, including improved photocatalytic activity 7,8,9 supercapacitor applications 10,11, and gas sensors 12,13. CuO is a p-type semiconductor with a band gap of 1.2 eV, a melting point of 1330 °C and a density of 6.4 g cm<sup>-3</sup>. CuO can be found in two important phases: cupric oxide (CuO) and cuprous oxide (Cu<sub>2</sub>O) 14. CuO can be synthesized by various methods such as chemical vapor deposition (CVD), sol-gel, spray pyrolysis, hydrothermal, pulsed laser deposition, etc. Depending on the physical or chemical strategies used, different sizes, dimensions and morphologies can be obtained 15. More stable phase of CuO can exist in numerous forms, such as nanoparticles, nanoplates, nanowires, nanoneedles, nanorods, nanoflowers and thin films 16. On the other hand, CuO lacks excellent electrical conductivity and rapid capacity decay, and its mechanical properties are limited compared to other oxides 17,18. Therefore, researchers have made many efforts to overcome its disadvantages by controlling the geometry of the nanostructure or by functionalization 19. Functionalization is a way to change the chemical characterization of a material by bringing nanoparticles into contact with the surface of a material, thereby introducing additional features and changing the surface chemistry of the material 20,21. Graphene oxide (GO) and reduced graphene oxide (rGO) have been suggested as promising candidates to improve CuO characterizations because of their superior thermal, electrical, and mechanical qualities 22 in addition to their size in the range of nanometer, large surface to volume ratio, and limited toxicity 23. Graphene is a two-dimensional hexagonal structure that can be oxidized to obtain GO, which is considered one of the best oxides used in recent years, with an energy gap of 2.2 eV 24. GO is a single-layer flake with more oxygen functional groups, easily dissolving in water and other solvents 25. This property is helpful in electronic applications 26. GO can be thermally or chemically reduced to obtain rGO. rGO will help improve its applications. The graphene derivatives are versatile materials and, therefore, could be used in various fields such as photovoltaic applications 27, nanomedicine 28, intelligent drugs 29,30, organic solar cells 31, and gas sensing 32. Various methods have been investigated for the synthesis of rGO/CuO and studied their properties and applications. Chandrama Sarkar and Swapan K. Dolui 33 achieved the preparation of CuO/rGO by hydrothermal method at 150 °C and explained the role of the catalyst in the reduction of 4/ NP. It was found from the results of FTIR and XRD that a weak diffraction peak related to rGO was observed and crumpled- like paper- surface of GO incorporated with Cu nanoparticles. Jae-Hun Kima et al. 34 synthesized CuO/rGO by electrospinning using copper acetate as a precursor. In this study, different ratios of rGO were loaded with CuO and showed an excellent response for H<sub>2</sub>S gas. In this area, rGO with p-type CuO can be an amazing materials. Dongzhi Zhang et al. 35 prepared a sensing film of rGO/CuO by hydrothermal method treated at 180 °C for 18 hours. In this work, the configuration includes three layers of rGO-CuO-rGO oxides exhibited best response for hydrogen gas than pure rGO or CuO. On the other hand, Suresh Sagadevan et al. 36 fabricated rGO-CuO in facile chemical method using reducing agent like N-dimethyl-formamide and ammonia. The SEM and TEM results showed that the particles in the spherical- shape with average size in the range of 60 nm. Based on the electrochemical data, the CuO/rGO nanocomposite shows great potential as a highly effective material for supercapacitor electronics. M. Iniya Pratheepa et al. 37 utilized NaOH as a reducing agent for reduction of CuO/rGO by chemical method. The FTIR findings confirmed the formation CuO/rGO with

band gap of 2.1 eV. The excellent electrochemical -capacitive conductivity of the produced rGO/CuO nanoparticles makes them an ideal electrode material for supercapacitors with high-performance. Semiconductor sensors, with low power consumption and excellent resistance measurement, are widely utilized in environmental, agricultural, industrial, energy, and medicine monitoring applications. Nanomaterials like CuO and rGO are widely used in semiconductor gas sensors. This is because rGO exhibits favorable physical and chemical characteristics that were mentioned previously. These attributes are advantageous for gas adsorption and redox reactions on the material's surface, which can be considered a main factor in enhancing the gas sensors' performance. Moreover, the heterojunctions formed by combining metal oxides with rGO can offer a pathways for carrier transport, leading to an increased number of active sites for gas adsorption 38. Industrial exhausts and wastes emit hazardous gases like ammonia (NH<sub>3</sub>), hydrogen sulfide (H<sub>2</sub>S), and carbon monoxide (CO), etc, leading to chronic health issues. This might significantly affect employees of life. Monitor these gasses regularly to ensure employee safety 39. NH<sub>3</sub> gas is a poisonous, colorless, and odorous gas that widely used in several industries, such as environmental, automotive, industrial, chemistry, and medical diagnostics. Ammonia is corrosive and extremely toxic, causing damage to the lungs, eyes, skin, and pharynx of those who inhale it. As a result, exceeding the acceptable inhalation level is of utmost importance to prevent contracting life-threatening illnesses 40. In this work, the reduction of GO and the production of rGO/CuO can be carried out by hydrothermal process at low temperature (100 °C) for four hours without any reducing agents. The influence of the preparation temperature on the reduction process was also investigated. Different amount of rGO were loaded with CuO to evaluate its effect on the carecterization of the nanocomposites. The nanocomposites were annealed at 400 °C for two hours and the effect of annealing on the structure and morphology was explained in detail. Additionally, we report on the dynamic response of rGO/CuO nanocomposites when exposed to NH<sub>3</sub> gas concentrations of 100 ppm at different operation temperatures.

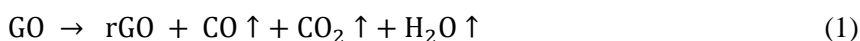
## 2. Materials

GO, Cu (No<sub>3</sub>)<sub>2</sub>.3H<sub>2</sub>O and NaOH were purchased from BDH Chemicals Ltd Poole England, ALPHA CHEMIKA in INDIA.

### Preparation methods

#### Preparation of reduced graphene oxide:

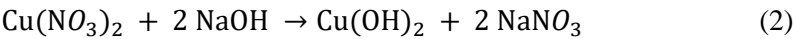
To thermally reduce GO, 2 gram of GO powder was dissolved in 100 mL of deionized water and sonicated for 30 minutes until all the powder was dispersed. This solution was then stirred for another 30 minutes, transferred to a sealed 100 mL autoclave, and heated in the oven at 100 °C for 4 hours. The product was washed five times with ethanol and distilled water, then dried at 100 °C for 2 hours according to equation 41:



Finally, the as-prepared nanocomposite was annealed in the electric furnace for 2 hours at 400 °C for further characterization.

#### Preparation of copper oxide:

To prepare CuO using the same method, 2 gram of  $\text{Cu}(\text{NO}_3)_2 \cdot 3\text{H}_2\text{O}$  was dissolved in 100 mL of deionized water and sonicated for 30 minutes. The color of a solution turns blue. Then (1 M) NaOH was slowly added with continuous stirring for another 30 minutes. The pH of the composites was tested and recorded to be 10. The solution was transferred to a 100 mL autoclave and heated at 100 °C for 4 hours. The obtained product was washed five times with ethanol and distilled water and then dried at 100° C for 2 hours. This reaction can be described as follows:



The as-prepared nanocomposite was annealed in the electric furnace for 2 hours at 400 °C for further characterization.

Preparation of reduced graphene oxide-copper oxide:

rGO/CuO was prepared using a hydrothermal process. First, a certain amount of GO powder was ultrasonically dispersed in 100 mL of deionized water for 30 minutes until the solution became homogeneous and brown. Then, 2 gram of  $\text{Cu}(\text{NO}_3)_2 \cdot 3\text{H}_2\text{O}$  was added to the obtained dispersion and stirred for 15 minutes. After that, (1 M) NaOH was slowly added with continuous stirring for another 20 minutes. The pH of the composites was tested and reported to be 9. Finally, the resulting mixture was transferred to a sealed 100 mL autoclave and heated in the oven at 100 °C for 4 hours. The composite was rinsed with ethanol and deionized water five times until pH 7 was attained. The final product was dried at 100 °C for 2 hours. The schematic diagram of the fabrication process is shown in (Figure 1). Different amounts of GO (0.5 gram, 1 gram, 2 gram) were used to explain its effect on the nanocomposites. The three samples were annealed in the electric furnace for 2 hours at 400 °C for further characterization.

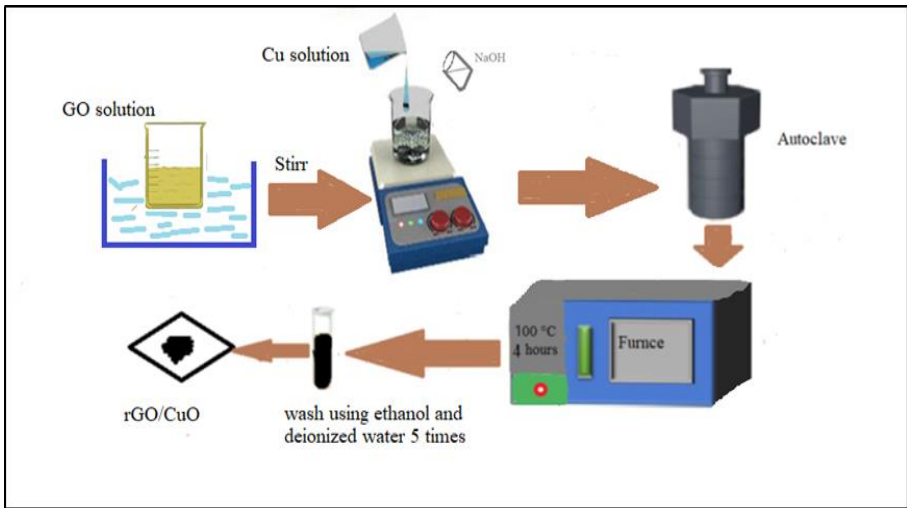


Figure1. Schematic diagram of the preparation process of rGO/CuO.

### 3. Characterization

The morphological, structural, elemental, and optical properties of the prepared composite were identified using field emission scanning electron microscopy (FESEM), X-ray diffraction (XRD), energy dispersive X-ray spectroscopy, elemental mapping (EDX), UV-visible spectroscopy, Fourier transform infrared spectroscopy (FTIR), and thermogravimetric analysis (TGA). The size of the crystallite D can be calculated using Scherer's equation 42,43:

$$D = \frac{K \lambda}{B \cos \theta} \quad (1)$$

Where D is the crystallite size in (nm); K is the shape factor (0.94);  $\lambda$  is the wavelength of the X-rays (1.5064 Å); B is half the maximum of full width. In addition, thermogravimetric analysis (TGA) tests are used to study the thermal stability of materials.

#### Fabrication of sensors

The glass was chosen as the substrate for depositing CuO and rGO/ CuO samples. A 2.5 cm × 2.5 cm glass substrate was cleaned with distilled water and alcohol, followed by 30 minutes of sonication, then dried on a hot plate for 10 minutes. The dip coating process was chosen for thin film deposition due to its ease of use and low cost. 100 mL was taken from each sample and placed in a baker. Glass substrates were immersed in a beaker containing solutions with an average velocity of 0.11 mm/s. The process entailed keeping the substrate in the beaker for 5 minutes and then withdrawing the sample at the same speed. Finally, the samples were dried on a hot plate at 90 °C for 10 minutes. The method is repeated five times for each sample to achieve a homogeneous thin coating. The deposited films are annealed in an electric furnace at 400°C for two hours. During the sensor fabrication process, two electrodes were sputtered onto the surface of the thin films using an appropriate mask. Gold fringe-shaped electrodes with a finger spacing of 400 μm and a fringe width of 350 μm were used. The schematic diagram of the semiconductor sensor is shown in Figure 2.

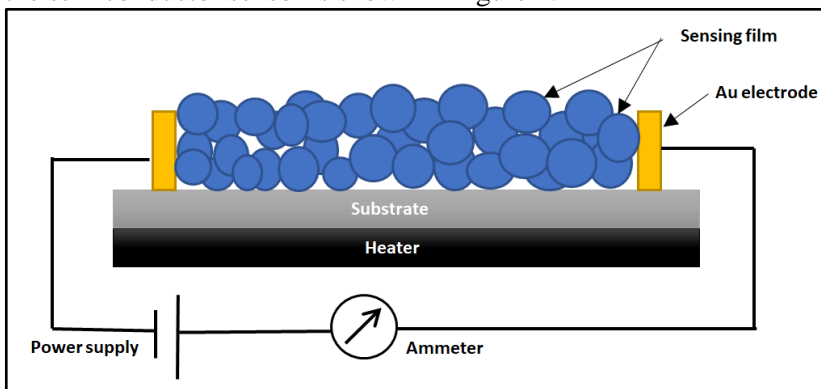


Figure 2. Schematic diagram of semiconductor sensor.

#### Measurement of Gas-Sensing

A handmade testing system was used to evaluate the detection and characterization of CuO and rGO/ rGO sensors. NH<sub>3</sub> gas was diluted with nitrogen and put into the enclosed chamber. Track NH<sub>3</sub> concentration with a mass flow meter and control it by air dilution. The sensor's electrical resistance was measured using a millimeter connected to a computer after placing

the sample in an enclosed chamber. The sensing measurements were taken at different temperatures. The resistance change measured the sensor's response. The following equation calculated the sensor's sensitivity upon exposure to NH<sub>3</sub> gas:

$$S \% = \left| \frac{R_a - R_g}{R_g} \right| * 100\% \quad (2)$$

Where  $[R_a \text{ and } R_g]$  are the sensor's resistance before and after exposure to the gas, respectively.

#### 4. Results

Structural properties of nano-composites:

X-ray diffraction (XRD) measurements confirmed the crystallization and composition of the as-prepared and annealed rGO, CuO, and rGO/CuO nanocomposites, as shown in Figure 2. From (Figure 3.a), it can be seen that the single phase of CuO (tenorite) can be observed from pure CuO with distinct diffraction peaks at  $2\theta$  equal to  $.508^\circ, 35.527^\circ, 38.758^\circ, 48.766^\circ, 53.563^\circ, 58.296^\circ, 61.557^\circ, 66.137^\circ, 68.076^\circ,$

$72.388^\circ, 75.127^\circ$  corresponding to (110), (-111), (111), (-202), (020), (202), (-113), (-311), (311), (220), (311), (-222) according to JCPDS card (00-005-0661) of CuO. The impact of GO on forming (rGO-CuO) nanocomposites can be demonstrated using XRD analysis of the samples (0.5 g, 1 g, 2 g of graphene oxide added copper nitrate). The samples are named (S1, S2 and S3) for simplicity. The XRD results of S1 show high-intensity peaks with a single copper oxide phase with lattice constant  $a=4.684 \text{ \AA}$ ,  $b=3.0425 \text{ \AA}$ ,  $c=5.129 \text{ \AA}$ , which is consistent with the data from JCPDS card (00-005-0661) matches CuO. The peaks around  $2\theta$  were presented in Table (1) and well agreed with previously published studies 38. A broad and weak additional reflection peak for the hexagonal structure of graphite corresponds to  $2\theta$  of  $42^\circ$  (100), due to low agglomeration and disordered stacking for rGO layers in the composites 44. In the case of S2, it is clear that the pronounced sharp peak at  $2\theta$  corresponding to  $36.54^\circ$  (211) indicates a cubic phase of Cu<sub>2</sub>O with a d-spacing of 2.5 nm, in addition to other small peaks at  $42.329^\circ$  (220) and  $77.417^\circ$  (422) plans accordance with the JCPDS card (00-002-1067). This result was similar to that reported previously 45 when the same method was used for preparation at  $100^\circ\text{C}$ . Two phases were observed for the S3 sample tenorite (CuO) and cuprite (Cu<sub>2</sub>O), and the tenorite phase was predominated. The peak corresponding to Cu<sub>2</sub>O was observed at  $29^\circ$  (200) according to the JCPDS card (00-002-1067) of Cu<sub>2</sub>O. Other weak and broad peaks related to GO appeared at  $16^\circ$  (001),  $26^\circ$  (002), and  $42^\circ$  (100). No other peaks indicated impurities in the three samples, indicating a successful preparation method. These results showed that GO and Cu (NO<sub>3</sub>)<sub>2</sub> were partially reduced to rGO and CuO. For the GO, it can be seen that GO has a clear peak at  $2\theta$  equal to  $13.7^\circ$  (001), according to the previous studies [39]. In addition to another new peak at  $25.65^\circ$  (002),  $42.76^\circ$  (100) and  $77.6^\circ$  (110) are related to the formation of rGO. These results agreed well with the graphite JCPDS card (00-001-0646). The appearance of a peak associated with GO indicates the incomplete reduction of graphene oxide at  $100^\circ\text{C}$ .



Table 1. XRD data of samples before and after annealing.

Sample	Before annealing					After annealing				
	2 $\theta$ (°)	d-spacing (Å)	(hkl)	FWHM (°)	Crystalline size (nm)	2 $\theta$ (°)	d-spacing (Å)	(hkl)	FWHM (°)	Crystalline size (nm)
S1	32.525	2.751	110	0.315	25.277	32.512	2.751	110	0.436	18.262
	35.450	2.530	-111	0.602	13.120	35.517	2.530	-111	0.504	15.672
	38.762	2.312	111	0.655	11.945	38.756	2.312	111	0.563	13.897
	42.33	2.133	100	0.43	17.987	48.751	1.866	-202	0.535	14.121
	48.737	1.866	-202	0.736	10.265	53.517	1.714	020	0.585	12.659
	53.543	1.714	020	0.635	11.661	58.298	1.581	202	0.605	11.973
	58.257	1.581	202	0.898	8.068	61.567	1.505	-113	0.599	11.895
	61.559	1.505	-113	0.823	8.658	66.129	1.410	-311	0.911	7.630
	66.118	1.410	-311	0.861	8.073	68.081	1.357	220	0.633	10.857
	68.089	1.357	220	0.835	8.230	72.448	1.304	311	0.643	10.405
	72.35	1.304	311	0.724	9.194	75.151	1.265	-222	0.742	8.859
	75.188	1.265	-222	0.918	7.158					
S2	36.541	2.463	111	0.233	33.803	432.56	2.751	110	0.219	36.353
	42.409	2.133	200	0.284	27.277	535.56	2.530	-111	0.261	30.259
	77.524	1.231	222	0.307	21.066	538.79	2.312	111	0.308	25.400
						748.78	1.866	202-	0.232	32.559
						953.56	1.714	020	0.316	23.431
						558.35	1.581	202	0.346	20.929
						761.61	1.505	-113	0.217	32.828
						866.14	1.410	-311	0.225	30.889
						968.11	1.357	220	0.4	17.178
						5472.4	1.304	311	0.316	21.173
						75.219	1.26	-222	0.213	30.847
S3	16.785	5.277	111	0.410	20.448	26.503	3.360	002	0.483	17.641
	26.608	3.347	002	0.700	12.177	29.425	3.033	110	0.146	58.695
	29.360	3.039	110	0.446	19.194	32.460	2.756	110	0.431	20.032
	32.326	2.767	110	0.508	17.000	35.562	2.522	-111	0.353	24.649
	35.471	2.751	-111	0.688	12.652	38.803	2.318	111	0.433	20.295
	38.714	2.530	111	0.715	12.277	46.41	2.511	-112	0.426	21.183
	42.592	2.312	100	0.480	18.543	48.758	1.959	-202	0.550	16.552
	44.962	2.017	-112	0.468	19.155	53.506	1.714	020	0.637	14.570
	48.593	1.959	-202	0.950	9.576	58.338	1.581	202	0.519	18.282
	51.207	1.866	112	0.200	46.038	61.632	1.505	-113	0.588	16.420
	53.586	1.778	020	0.720	12.894	66.822	1.410	-311	0.948	10.441
	58.169	1.714	202	0.542	17.490	68.061	1.357	220	0.742	13.482
	61.422	1.581	-113	0.620	15.549	72.390	1.304	311	0.827	12.419
	66.062	1.505	-311	0.800	12.381	75.111	1.265	-222	0.758	13.803
	68.581	1.410	220	0.400	25.031					
	72.310	1.357	311	0.540	19.014					
	75.436	1.265	-222	0.567	18.492					
CuO	32.508	2.751	110	0.406	21.293	32.423	110	2.758	0.400	21.582
	35.527	2.524	-111	0.584	14.923	35.422	111	2.531	0.576	15.114
	38.758	2.312	111	0.653	13.455	38.669	111	2.362	0.649	13.543
	48.766	1.866	-202	0.747	12.174	48.665	-202	1.869	0.644	14.127
	53.563	1.710	020	0.745	12.463	53.361	020	1.751	0.690	13.452
	58.296	1.582	202	0.993	9.559	58.241	202	1.583	0.688	13.788
	61.557	1.506	-113	0.931	10.363	61.486	-113	1.507	0.793	12.161
	66.137	1.410	-311	1.066	9.280	66.054	-311	1.414	1.022	9.672
	68.076	1.376	220	0.882	11.336	67.956	220	1.378	0.858	11.646
	72.388	1.304	311	1.064	9.657	72.396	311	1.304	0.985	10.428
	75.127	1.264	-222	1.223	8.554	75.052	-222	1.265	1.038	10.068

rGO	13.155	6.724	001	2.532	3.298	11.691	001	7.652	0.280	29.689
	25.490	3.350	002	3.686	2.307	25.504	002	3.489	0.381	22.278
	42.578	2.132	100	1.546	5.759	48.775	102	1.865	0.373	24.394
	46.070	1.968	101	0.160	56.329					
	59.524	1.551	103	0.200	47.771					
	77.699	1.288	110	1.440	7.395					

To illustrate the impact of the annealing process on the nanocomposite, all samples underwent annealing in an electric furnace at a temperature of 400 °C for 2 hours. From (Figure 3. b), the XRD results for pure CuO, S1, and S3 showed increased peak intensity and sharpness, indicating increased crystallites after annealing. However, after thermal treatment, S2 showed a different cupric oxide (CuO) phase. The clear peak of rGO becomes very weak or disappears in the three samples. This can be attributed to the high intensity of CuO that suppressed rGO, which is consistent with 44,46,47. The reduction of GO was incomplete upon annealing, resulting in the weak diffraction peak. The size of the nanocomposites could be significantly altered by manipulating the quantity of GO present in the nanocomposites. These results were consistent with those in 48. Furthermore, the average crystal size increased after annealing for all samples and resulted in the growth of CuO crystals, which is consistent with previous studies 49,50. Table (1) shows the XRD data for all samples before and after annealing.

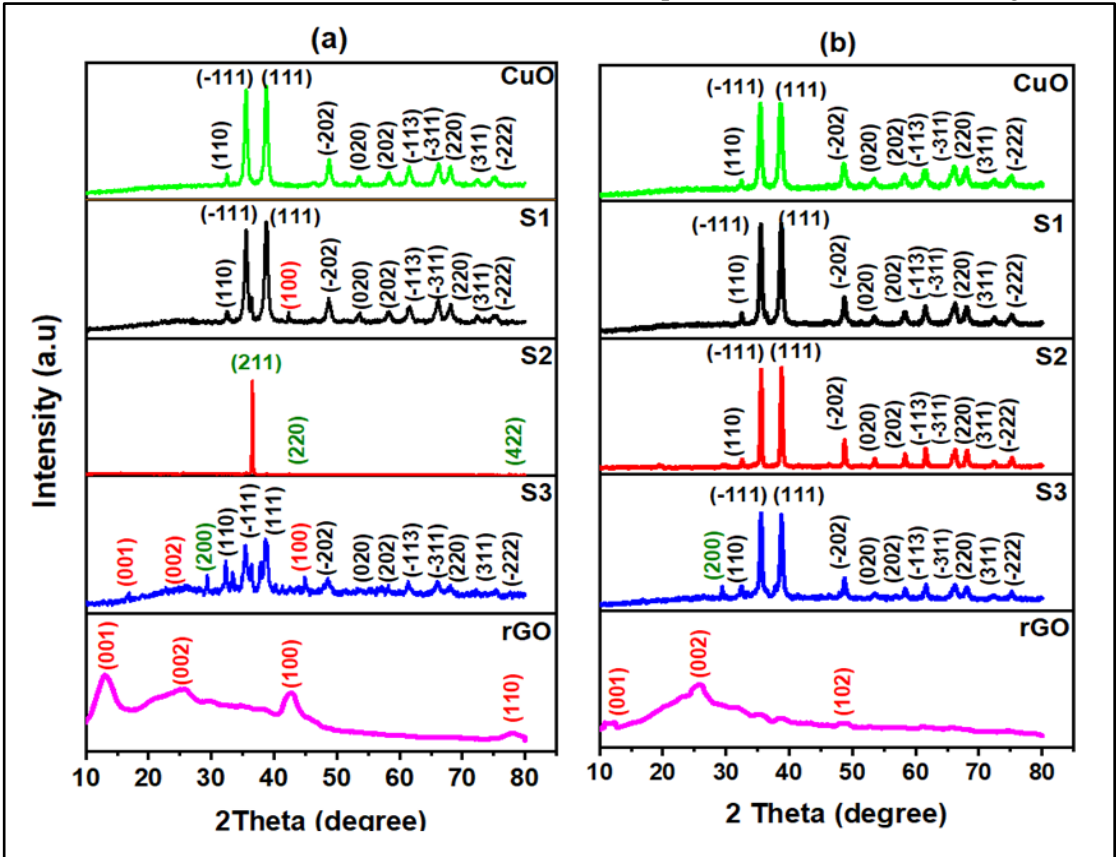
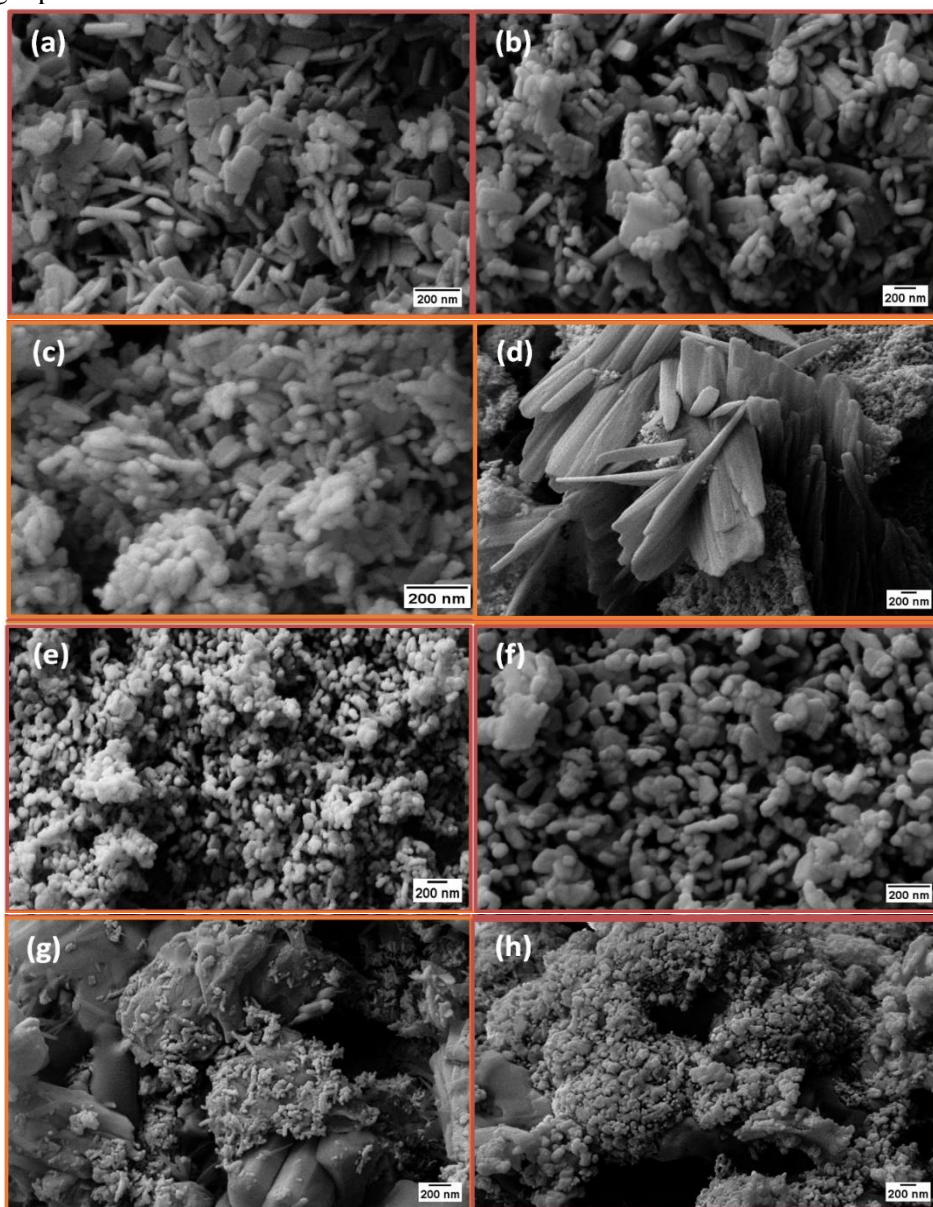


Figure 3. XRD of CuO, CuO/rGO, and rGO nanocomposites (a) as-prepared, (b) after annealing at 400 °C.



### Morphological and EDX analysis of the nano-composites

The morphology of the prepared and annealed samples was analyzed in FESEM at high resolution, as shown in Figure 4. Figure (4. a,b) indicates the formation of CuO nanorods. After annealing, these structures agglomerated and condensed on the surface, appearing as larger particles. The influence of the quantity of GO on the rGO/ CuO nanocomposites was demonstrated in Figure (4c-h). S1 had a rod-shaped morphology on its surface. Upon annealing at a temperature of 400 °C, the nanorod structure undergoes aggregation, resulting in bigger particles and an unfamiliar structure.



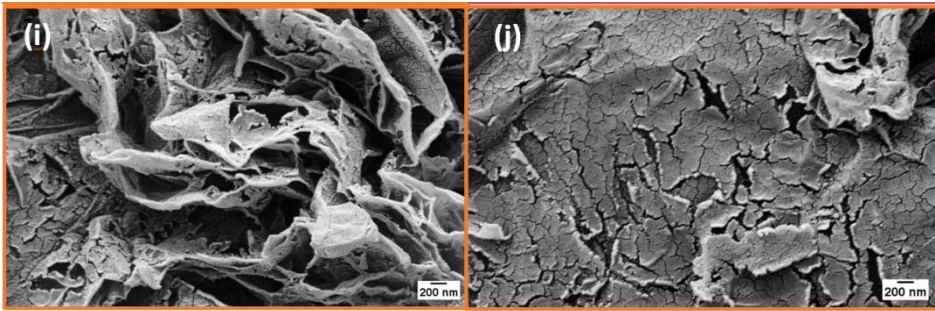


Figure 4. FESEM images of (a,b) CuO, (c,d) S1, (e,f) S2, (g,h) S3, and (i,j) rGO before and after annealing, respectively.

After increasing the amount of GO to 1 g, the nanocomposite's shape became spherical and larger after annealing. When the weight fraction of GO reaches 2 g, a semi-rod-like shape is formed, which covers the surface of the rGO sheets. After thermal treatment, this structure aggregates into large agglomerations in a spherical shape. Therefore, the number of small particles decreased and consequently increased particle size. The role of NaOH in the reaction was to establish contact between GO and CuO through hydrothermal treatment, thereby inducing electrons on the surface of GO. At this stage, the reduction of Cu<sup>+2</sup> and GO occurs, and CuO and rGO nanocomposites are formed due to the effect of temperatures mentioned in previous works 51. All three samples were observed to have sizes in the nanoscale range. Figure (4i,j) shows the FESEM images of the as-prepared and annealed rGO. The rGO layers were agglomerated with each other in a plate-like shape, and this structure contained more defects due to the decomposition of oxygen groups after thermal annealing, indicating a reduction of GO. To prove the interstitial structure (elementary structure) of the synthetic composites previously prepared by hydrothermal method, EDX was performed and showed that Cu, O, and C are the main elements for samples Cu, S1, S2, S3, and rGO, and no other impurities are shown in Figure 5. This indicates the successful production of nanocomposites. The percentages of Cu, O, and C are shown in Table (2). The decrease in copper content in samples S1, S2, and S3 corresponds to an increase in GO concentration in the nanocomposite.

Table 2. EDX spectra of as-prepared samples.

Sample	Cu wt. %	C wt. %	O wt. %
<b>CuO</b>	81.6	-	18.4
<b>S1</b>	70.7	10.9	18.4
<b>S2</b>	52.5	25.7	21.8
<b>S3</b>	36.1	39.2	24.7
<b>rGO</b>	-	83.8	16.2

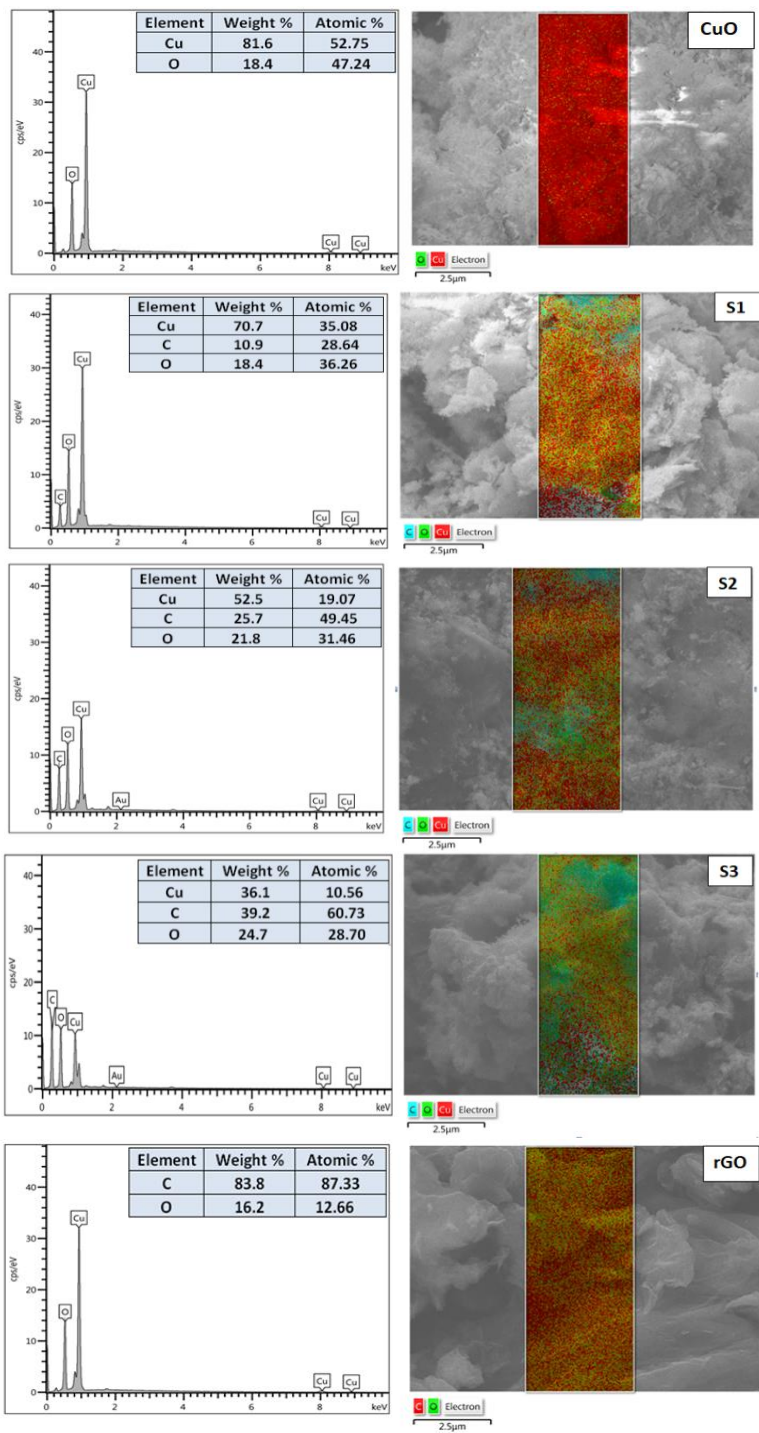


Figure 5. EDX spectrum and elemental mapping for CuO, rGO/ rGO, and rGO.

### Optical properties of nanocomposites

The UV-visible absorption spectrum of all samples before and after annealing is shown in Figure 6. This spectrum was recorded for the range (190-1200 nm). From Figure 6(a), the absorption peak of samples S1, S2, and S3 is red-shifted at 293 nm, while the absorption peak of CuO appears at around 354 nm and of rGO at about 230,325 nm, indicating ( $\pi^*-\pi^*$ ) and ( $n-\pi^*$ ) transitions of the double bonds between ( $C=C$ ) and ( $C-O$ ) in the graphite framework 52. These two peaks appeared in reduced graphene oxide, indicating the incomplete reduction of graphene oxide. There was no significant effect of annealing on the first three samples, apart from a slight increase in absorbance. Furthermore, the absorption of CuO increased, and the peak appeared at around 324 nm. After annealing, a single peak at around 231 nm was observed for rGO, indicating a reduction of GO.

### Thermogravimetric analysis (TGA):

Figure 7 shows the thermal stability of materials under a nitrogen atmosphere with a temperature rise of 50 °C [min]<sup>-1</sup> before and after annealing. TGA analysis of CuO showed a slight weight reduction of about 2.25% between 100 °C and 400 °C, which is due to the evaporation of volatile compounds. After reaching a temperature of 450 °C, no additional mass loss was recorded, save for a marginal decrease of 1%. This suggests that the thermal stability of CuO is approximately 450 °C. Observations of samples S1 and S2 indicate that a modest weight reduction, ranging from 5% to 7%, occurs at temperatures below 450 °C. This weight loss can be attributed to the evaporation of water in the nanocomposites. After that, the weight loss increased to about 12%, indicating the degradation of the oxygen-containing functional groups in the composite 47. No further weight loss was observed after 800 °C. However, in the case of S3, the weight loss due to absorbed moisture increased to 11% as the GO ratio in the nanocomposite increased, at around 150 °C. The gradual weight loss was 42% at 800 °C due to the combustion of carbon in the composite. The gradual weight loss was observed during the TGA of rGO between 100 °C and 200 °C. After 200 °C, there was a rapid weight loss of around 27.4% up to 250 °C in the second step. This is due to the evaporation and reduction of the carboxyl and hydroxy groups. Thermal stability was observed after 250 °C and a slight weight loss of about 4% up to 450 °C. Gradual weight loss continues until 700 °C, and the total weight loss reaches 46%.

### FTIR spectroscopy

FTIR spectroscopy is utilized to identify the vibrational frequencies in the synthesized CuO, rGO/CuO, and rGO, as depicted in Figure 8. The peak detected at 3742 cm<sup>-1</sup> was ascribed to the stretching vibrations of O-H bonds induced by water absorption in the composites. The peak observed at 2360.9 cm<sup>-1</sup> in CuO is attributed to the stretching vibrations of CH<sub>2</sub> 47. The absorption peak seen at 659 cm<sup>-1</sup> was likely attributed to the vibration of the Cu-O bond in the monoclinic phase of CuO 53. The rGO-CuO sample exhibits a distinct absorption band at 3447 cm<sup>-1</sup>, attributed to the stretching and bending vibrations of the hydroxyl groups and water molecules on the surface.

Furthermore, 1475 cm<sup>-1</sup> and 520 cm<sup>-1</sup> peaks confirmed that the cuprous ions were securely attached to the graphene oxide layers 54. The occurrence of a peak of about 1508 cm<sup>-1</sup> in the rGO sample can be attributed to the existence of C=C in a graphene oxide sheet. Additional



peaks at 1161 cm<sup>-1</sup>, 918 cm<sup>-1</sup>, and 605 cm<sup>-1</sup> can be attributed to rGO, indicating that the GO underwent partial reduction<sup>55</sup>.

### Sensors response

The sensors' responsiveness was evaluated under different temperature conditions. The sensing performance of the rGO/ CuO nanocomposites, synthesized at 100 °C, was evaluated. The chamber was purged with ultra-pure nitrogen gas N<sub>2</sub> (99.9%), and measurements were taken at various temperatures (room temperature, 100 °C, 200 °C). The rGO/CuO sensors were positioned within the chamber, and Ammonia gas was introduced into the chamber at the desired concentrations. The sensing performance of the rGO/CuO sensors was evaluated by applying a voltage of 500 millivolts at ambient temperature. The sensor's sensitivity to NH<sub>3</sub> gas was assessed using eq. (4). Figure 9 illustrated the rGO/CuO sensors response to 100 ppm NH<sub>3</sub> gas at various temperatures. The sensor sensitivity of the three samples exhibited higher values at room temperature, with recorded values of 5.95, 9.13, and 6.42 for samples S1, S2, and S3, respectively, as evident from Figure 9 (a-c). The sensing response decreased when the temperature was subsequently raised to 100 °C. When the temperature was raised to 200 °C, there was a little increase in sensitivity for samples S1, S2, and S3. This change can be related to the release of oxygen at higher temperatures due to desorption <sup>56</sup>. The optimal operating temperature for rGO/CuO sensors is around room temperature. Results showed that sensor response is highly influenced by the weight ratio of GO in nanocomposites. A comparison was made between hydrothermally synthesized CuO and rGO/CuO sensor gas. Figure 10 shows that the sensitivity of CuO increased with higher sensor temperatures, reaching 5.32 at 200 °C. The respond of S2 sensor was 9.13 at room temperature, significantly higher than other rGO/CuO sensors and up to threefold the CuO sensor (3.16) (see Figure 11). The rGO-incorporated CuO exhibited significantly improved sensing responsiveness compared to pure CuO. Additionally, sample S2 showed rapid response and recovery time of 21 s and 15 s, faster than previous works at room temperature <sup>57</sup>. Table 3 displays all sensors' estimated sensitivity, response, and recovery times.

Table 3 Sensitivity, response and recovery times of rGO/CuO nanocomposites and CuO.

Sample	Operation Temperature(°C)	S%	Res. time (sec)	Rec. Time (sec)
S1	RM	5.95	27	30
	100	2.46	34	31
	200	3.35	30	34
S2	RM	9.31	21	15
	100	5.66	26	29
	200	5.94	21	11
S3	RM	6.42	18	25
	100	3.55	33	19

	200	5.83	25	15
	RM	3.16	15	38
CuO	100	4.49	28	18
	200	5.32	22	20

Gas sensing mechanism

The adsorption of target gases on their surfaces alters the resistance of gas sensors. This phenomenon constitutes the fundamental concept of the detection process of metal-oxide gas sensors 58. Initially, we will discuss the sensing process employed in the bare CuO gas sensor. CuO is a p-type semiconductor characterized by the presence of holes as its primary charge carriers. Within the air, oxygen molecules with a significant electron affinity (0.43 eV) readily adhere to the sensor surfaces and extract electrons from the surfaces of CuO; as a result, adsorbed oxygen ions will appear on the surface in molecular (O<sub>2</sub>) and atomic (O<sup>-</sup> and O<sub>2</sub><sup>-</sup>) forms as shown in eq.(4-7)59:



Consequently, the rise in hole carrier concentrations leads to decreased resistance. After introducing NH<sub>3</sub> gas, electrons will be released, interacting with CuO. Consequently, the amount of hole carriers decreases, leading to an increase in the resistance of CuO. The rGO/CuO composites exhibited remarkable reactivity to NH<sub>3</sub>. rGO/CuO has p-type semiconducting behaviors, with the conductance primarily dependent on rGO; therefore, the oxygen functional groups in rGO withdraw electrons from NH<sub>3</sub> gas. The presence of dangling bonds and surface defects in rGO increases the number of sites available for NH<sub>3</sub> adsorption. When rGO and CuO come into contact, electrons are transported from rGO to CuO because of the disparity in their work functions (5.3 eV for CuO and 4.7 eV for rGO) 57, causing a bending of the band at the rGO/CuO interface. Consequently, the concentration of hole carriers decreases while the resistance of rGO/CuO increases. Nevertheless, when the concentration of rGO is high enough, it creates an additional pathway for current flow, leading to a more extensive conduction path along the rGO. This, in turn, decreases the initial resistance and consequently impacts the sensor's response time compared to the optimal quantity of rGO.

5. Conclusions

A simple and cost-effective strategy for preparing CuO/rGO nanocomposites was reported. The Cu and GO were reduced using a hydrothermal method at a temperature of 100 °C. CuO and rGO were verified using XRD, EDS, and FTIR analysis and further improved using FESEM. The average particle size was calculated using Scherer's equation and was found to increase with increasing GO construction. Two structures were observed in FESEM results:



rod and spherical shapes corresponding to the GO amount in the composite. The results of TGA revealed that the as-prepared samples (S1, S2, S3) were less stable as GO weight increased compared to pure CuO and more than rGO. It was found from the results that the amount of rGO has a significant effect on the sensing performance of NH<sub>3</sub> gas. The rGO/CuO sensors exhibited a good response of about 5.95, 9.13, and 6.42 for samples S1, S2, and S3, respectively, compared to pristine CuO, which was about 3.16 at room temperature. The S2 nanocomposite sensor demonstrated a 21 s response and 15 s recovery time to 100 ppm NH<sub>3</sub> at 30 °C, significantly improving compared to earlier studies.

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